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High Performance and Low Powerful Adder Design Based Static **Topologically Compressed 21 Transistor Flip-Flop**



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Abstract:

An extremely low-power flip-flop (FF) named topo- logically-compressed flip-flop (TCFF) is proposed. As compared with conventional FFs, the FF reduces power dissipation by 75% at 0% data activity. This power reduction ratio is the highest among FFs that have been reported so far. The reduction is achieved by applying topological compression method, merger of logically equivalent transistors to an unconventional latch struc- ture. The very small number of transistors, only three, connected to clock signal reduces the power drastically, and the smaller total transistor count assures the same cell area as conventional FFs. In addition, fully static full-swing operation makes the cell tolerant of supply voltage and input slew variation. An experimental chip design with 40 nm CMOS technology shows that almost all con- ventional FFs are replaceable with proposed FF while preserving the same system performance and layout area.

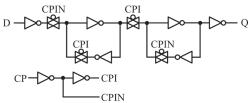
Index Terms:

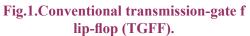
Flip-flops, low-power, VLSI.

I. INTRODUCTION:

HE mobile market keeps on expanding. In addition to the conventional mobile phone, digital camera, and tablet PC, development of various kinds of wearable information equipment or healthcare associated equipment has newly prospered in recent years. In those kinds of battery-working equipment, reduction of power is a very important issue, and demand for power reduction in LSI is increasing. Based on such background, various kinds of circuit technique have already been proposed.

In LSI, generally more than half of the power is dissipated in random logic, of which half of the power is dissipated by flip-flops (FFs). During the past dozen years, several low-power FFs have been rushed into development. However, in actual chip design, the conventional FF is still used most often as a preferred FF because of its well-balanced power, performance and cell area. The purpose of this paper is to present a solution to achieve all of the goals: power reduction without any degradation of timing performance and cell area. In Section II, we review existing low-power FFs. In Section III, we show our design approach. In Section IV, we propose FF realization with a new methodology. In Section V,





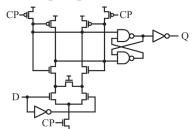


Fig. 2. Differential sense-amplifier flip-flop (DiffFF).

The detailed power and performance characteristics are shown compared to other FFs. In Section VI, we show the effect of the proposed FF in actual chip design by experimental layout. Finally, in Section VII, we show the

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way to apply the proposed FF effectively to various systems in view of power and performance.

II. BACKGROUND:

In this section, we analyze problems on previously reported typical low-power FFs with comparison to a conventional FF shown in Fig. 1.Fig. 2 shows a typical circuit of differential sense-amplifiertype FF (DiffFF) [1]–[3]. This type of circuit is very effective to amplify small-swing signals, so is generally used in output of memory circuits. In this FF, however, the effect of power re- duction goes down in the condition of lower data activity, be- cause these kinds of circuits have pre-charge operation in every clock-low state. Moreover, if we use reduced clock swing, a cus- tomized clock generator and an extra bias circuit are necessary.Fig. 3 shows a circuit of conditionalclocking type FF (CCFF) [4]–[6]. This circuit is achieved from a functional point of view. The circuit monitors input data change in every clock cycle and disables the operation of internal clock if input data are not changed. By this operation, power is reduced when input data are not changed. But unfortunately, its cell area becomes almost double that of the conventional circuit shown in Fig. 1.

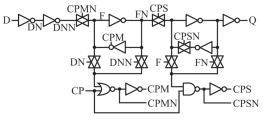


Fig. 3. Conditional-clocking flip-flop (CCFF).

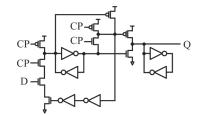


Fig. 4. Cross-charge control flip-flop (XCFF).

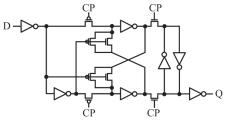


Fig. 5. Adaptive-coupling flip-flop (ACFF).

And mainly due to this size issue, it becomes hard to use if the logic area is relatively large in the chip.Fig. 4 shows the circuit of cross-charge control FF (XCFF) [7]. The feature of this circuit is to drive output transistors separately in order to reduce charged and discharged gate capaci- tance. However, in actual operation, some of the internal nodes are pre-set with clock signal in the case of data is high, and this operation dissipates extra power to charge and discharge internal nodes. As a result, the effect of power reduction will decrease. Circuits including preset operation have the same problem [8]. The adaptivecoupling type FF (ACFF) [9], shown in Fig. 5, is based on a 6-transistor memory cell. In this circuit, instead of the commonly used double-channel transmission-gate, a single- channel transmission-gate with additional dynamic circuit has been used for the data line in order to reduce clock-related tran- sistor count.

However, in this circuit, delay is easily affected by input clock slew variation because different types of singlechannel transmission-gates are used in the same data line and connected to the same clock signal. Moreover, characteristics of single-channel transmission-gate circuits and dynamic circuits are strongly affected by process variation. Thus, their optimiza- tion is relatively difficult, and performance degradation across various process corners is a concern.Let us summarize the analysis on previously reported low-power FFs. For DiffFF [1] and XCFF [7], pre-charge operation is a concern especially in lower data activity. As regards CCFF [4], its cell area becomes a bottleneck to use. And for ACFF [9], tolerance for input clock slew variation becomes subject to resolve.

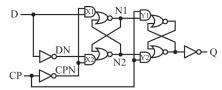


Fig. 6. Example of combinational type FF.

III. DESIGN APPROACH

In order to reduce the power of the FF while keeping com- petitive performance and similar cell area, we tried to reduce the transistor count, especially those operating with clock signals, without introducing any dynamic or pre-charge circuit. The power of the FF is mostly dissipated in the operation of clock-related transistors, and reduction of transistor count is effective to avoid cell



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area increase and to reduce load capaci- tance in internal nodes. In the conventional FF shown in Fig. 1, there are 12 clock-related transistors. To reduce clock-related transistor counts directly from this circuit is quite difficult. One reason is because transmission-gates need a 2-phase clock signal, thus the clock driver cannot be eliminated. Another reason is that transmission-gates should be constructed by both PMOS and NMOS to avoid degradation of data transfer characteristics caused by single-channel MOS usage.

There- fore, instead of transmission-gate type circuit, we start with a combinational type circuit as shown in Fig. 6. To reduce the transistor-count based on logical equivalence, we consider a method consisting of the following two steps. As the first step, we plan to have a circuit with two or more logically equivalent AND or OR logic parts which have the same input signal com- bination, especially including clock signal as the input signals. Then, merge those parts in transistor level as the second step.

IV.PROPOSED TOPOLOGICALLY-COM-PRESSED FLIP-FLOP: A.Proposed FF and Transistor Level Compression:

After investigating many kinds of latch circuits, we have set up an unconventionally structured FF, shown in Fig. 7. This FF consists of different types of latches in the master and the slave parts. The slave-latch is a well-known Reset-Set (RS) type, but the master-latch is an asymmetrical single data-input type.

The feature of this circuit is that it operates in single phase clock, and it has two sets of logically equivalent input AND logic, X1 and Y1, and X2 and Y2. Fig. 8 shows the transistor-level schematic of Fig. 7. Based on this schematic, logically equivalent transis- tors are merged as follows. For the PMOS side, two transistor pairs in M1 and S1 blocks in Fig. 8 can be shared as shown in Fig. 9.

When either N3 or CP is Low, the shared common node becomes VDD voltage level, and N2 and N5 nodes are controlled by PMOS transistors gated N1 and N4 individually. When both N3 and CP are High, both N2 and N5 nodes are pulled down to VSS by NMOS transistors gated N3 and CP. As well as M1 and S1 blocks, two PMOS transistor pairs in M2

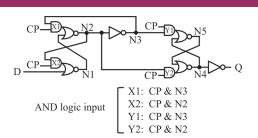


Fig. 7. Schematic diagram of proposed FF.

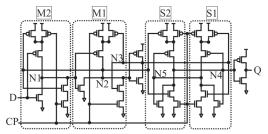


Fig. 8. Transistor level schematic of Fig. 7.

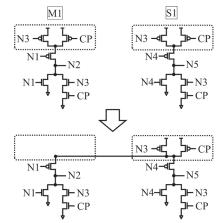


Fig. 9. Transistor merging in PMOS side.

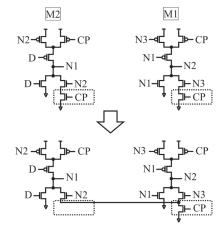


Fig. 10. Transistor merging in NMOS side.

and S2 blocks are shared. For the NMOS side, transistors of log- ically equivalent operation can be shared as well. Two transis- tors in M1 and M2 blocks in Fig. 10 can be shared. Transistors in S1 and S2 are shared as well.

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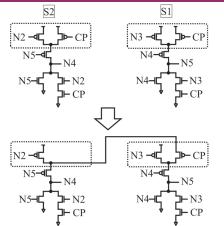


Fig. 11. Further transistor merging in PMOS side.

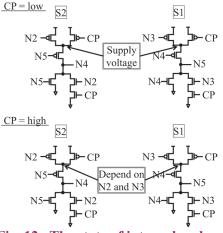


Fig. 12. The state of internal nodes.

Further in the PMOS side, CP-input transistors in S1 and S2, shown in Fig. 11, can be merged, because N2 and N3 are log- ically inverted to each other. When CP is Low, both nodes are in VDD voltage level, and either N2 or N3 is ON. When CP is High, each node is in independent voltage level as shown in Fig. 12. In consideration of this behavior, the CP-input transis- tors are shared and connected as shown in Fig. 11.

The CP-input transistor is working as a switch to connect S1 and S2. This process leads to the circuit shown in Fig. 13. This circuit consists of seven fewer transistors than the original circuit shown in Fig. 8. The number of clock-related transistors is only three.

Note that there is no dynamic circuit or pre-charge circuit, thus, no extra power dissipation emerges. We call this re- duction method Topological Compression (TC) method. The FF, TC-Method applied, is called Topologically-Compressed Flip-Flop (TCFF).

B.Cell Operation:

Fig. 14 shows simulation waveforms of the circuit shown in Fig. 13. In Fig. 13, when CP is low, the PMOS transistor con- nected to CP turns on and the master latch becomes the data input mode. Both VD1 and VD2 are pulled up to power-supply level, and the input data from D is stored in the master latch. When CP is high, the PMOS transistor connected to CP turns.

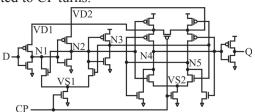


Fig. 13. Transistor level schematic of topologicallycompressed flip-flop (TCFF).



Fig. 14. Waveform on SPICE simulation.

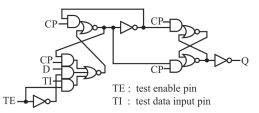
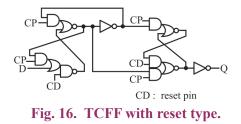


Fig. 15. TCFF with scan type.



slave latch becomes the data output mode. In this condition, the data in the master latch is transferred to the slave latch, and then outputted to Q. In this operation, all nodes are fully static and full-swing. The current from the power supply does not flow into the master and the slave latch simultaneously because the master latch and the slave latch become active alternately. Therefore, timing degradation is small on cell performance even though many transistors are shared with no increase in transistor size.

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C. Cell Variation:

LSI designs require FFs having additional functions like scan, reset, and set. The performance and cell area for these cells are also important. TCFF easily realizes these cells with less transistor-count than conventional FFs. The circuit diagrams of TCFF with scan, reset, and set are shown in Figs. 15–17. Each circuit can be designed with similar structure, and these FFs also have three transistors connected to CP so the power dissipation is nearly the same as that of TCFF. Detailed characteristics are shown in Section V.

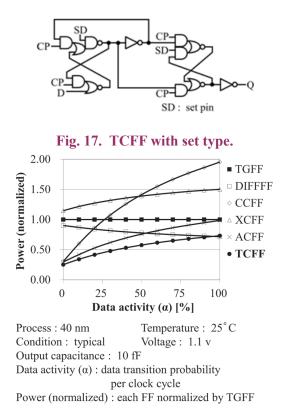


Fig. 18. Power simulation results of TCFF and other FFs.

V. PERFORMANCE SIMULATION:

The performance of TCFF is demonstrated by SPICE simula- tion with 40 nm CMOS technology. For comparison with other FFs, the same transistor size is applied for every transistor in each FF including TCFF in order to simulate the same condi- tions. Some standard values are assumed for transistor sizes for the purpose of comparison; 0.24 m for width and 0.04 m for length in PMOS, and 0.12 m for width and 0.04 m for length in NMOS.

Fig. 18 shows the normalized power dissipation versus data activity compared to other FFs. TCFF consumes the least power among them in almost all ranges of data activity. Average data activity of FFs in an LSI is typically between 5% and 15%. The power dissipation of TCFF is 66% lower than that of TGFF at10% data activity. In the same way at 0% data activity, it is75% lower. Table I summarizes the transistor-count, the CP-Q delay, the setup/ hold time, and the power ratio of each FF. As for delay, TCFF is almost the same as the conventional FF, and better than other FFs. Setup time is the only inferior parameter to the conventional FF, and about 70 ps larger than the value of the conventional one. For hold time, TCFF is better than the conventional FF. In summary, only setup time is large, but TCFF keeps competitive performance to the conventional and other FFs.Fig. 19 shows the supplyvoltage dependence of the CP-Qdelay. TCFF is possible to operate down to 0.6 V supply voltage due to essentially fully-static function. Though TCFF operates with single phase clock signal, a clock buffer is not necessary. The circuit is directly driven from a clock pin. Fig. 20 shows the clock-input-slew dependence of the CP-Q delay. ACFF.

TABLE I:PERFORMANCE COMPARISONOF TCFF AND OTHER FFS

-		-			
	#Tr.	CP-Q delay	setup	hold	power (α=10%)
TGFF	24	183	38	-15	1.00
DiffFF	22	209	-7	70	0.87
CCFF	42	225	173	-135	0.60
XCFF	21	221	-26	57	1.22
ACFF	22	176 139		-93	0.42
TCFF	21	176	105	-69	0.34
#Tr. : nu CP-Q de setup and power : Unit of p	apacitanc imber of lay : ave l hold : d ratio nor erformar	transistor transistor trage CP-to efined at 0 10% from malized by	o Q delay CP-to-Q d n stable va	of D=hig elay incr	gh and low eased
CB-0 0000 0000 0000 CB-0 0 0001 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0		0.7 0.8 VD	0.9 D [V]	1.0 1.7	■ TGFF □ DIFFFF ◇ CCFF △ XCFF × ACFF ● TCFF

Fig. 19. Supply voltage dependency.

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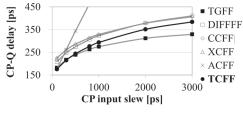
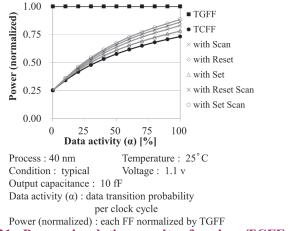


Fig. 20. Input slew dependency

has more clock-input-slew dependence compared to other FFs, thus it becomes difficult to use in large input transition time. The characteristics of TCFF are stable and the second best following TGFF.Fig. 21 shows the normalized power versus the data activityfor six varieties of TCFF including the basic type, and Table II shows performances of various TCFFs in the same conditions as Table I. Every cell inherits the strength of the original TCFF cell structure. No difference is observed among cell variations.Fig. 22 shows the layout of TGFF and TCFF with scan. Because TCFF needs more wiring resources for master and slave latch in the layout, it uses metal3 as compared to TGFF using up to metal2. But because the number of transistors in TCFF is fewer than the TGFFs, TCFF can be realized in slightly smaller cell area than the conventional one. In this layout, the area is adjusted to grid base design, resulting in the same area as the conventional one. Thus, it is easy to replace the conventional FF with TCFF if the cell replacement process is executed after pre-layout and timing analysis. In this section, TCFF's lowest power dissipation, competitive performance,





TABLEII:PERFORMANCECOMPARI-SONS OF VARIOUSTCFFS:

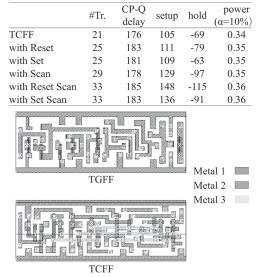


Fig. 22. The cell layout with scan.

and cell area are explained. In the next section, how effectively TCFF is applied to actual chip design is shown by placement and routing experiment.

VI. EXPERIMENTAL CHIP LAYOUT:

In order to estimate the effect when applying to a chip design, an experimental netlist is implemented in a 2 mm square chip by utilizing commercial logic synthesis and P&R tool. Fig. 23 shows the layout and outline of the experimental chip. It consists of random logic, SRAM, analog, and I/O. The random logic consists of FFs, clock drivers, and other logic.

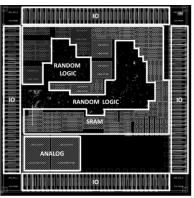
In order to verify how TCFF is effectively applied to chip design, two types of front-end cell libraries are prepared. One is a conventional set with TGFF, and the other is a set including TCFF in addition to TGFF. Using these two libraries, logic synthesis and P&R are



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TABLE III:EXPERIMENTAL CHIP LAYOUT DESIGN SUMMARY

		Original (TGFF only)			TGFF add TCFF		
K=1024		#Cell [K]	#Tr [K]	Area [mm ²]	#Cell [K]	#Tr [K]	Area [mm ²]
	TGFF	61.5	1850.9	0.228	1.3	43.3	0.005
Design	TCFF	-	-	-	60.2	1624.3	0.222
	Clock driver	1.5	22.8	0.003	1.4	22.2	0.003
	Other logic	278.7	2294.2	0.300	281.1	2364.5	0.308
Total		341.6	4167.9	0.530	344.0	4054.4	0.538
Ratio(vs Original)		1.0	1.0	1.0	1.007	0.973	1.013
Ratio of FF(#Tr)		0.44			0.41		
#Cell (TCFF/total FF)		-			0.98		



Process : 40 nm Chip size : 2 mm × 2 mm Cell variation : SRAM, Analog, I/O, Random logic Clock frequency : 250 MHz Number of gate in Random logic : 1M Flip-flop in Random logic : 44 %



Lausistor number 4,000 - 3,000 - 1,000 - 0	TGFF Clock driver Other logic	TCFF TGFF Clock driver Other logic	
- 0 -	Conventional	with TCFF	
□ TCFF	0	1624	
□ TGFF	1851	43	
Clock driver	23	22	
□ Other logic	2294	2365	

Fig. 24. Transistor count of random logic area with and without TCFF.

executed independently and those results are compared. In logic synthesis, the power-reduction option is highly applied.Fig. 24 and Table III show the logic synthesis and P&R re- sults at 250 MHz clock frequency. After applying the library in- cluding TCFF, 98% of TGFFs which occupy 44% of the random logic are replaced by TCFFs. Almost all TCFFs meet the timing constraints despite TCFF having larger setup time of 105 ps in- stead of 38 ps of TGFF as shown in Table I.

Volume No: 3 (2016), Issue No: 1 (January) www.ijmetmr.com As regards area size, only 1.3% increased with the TCFFincluded library even though TCFF uses one more metal layer than TGFF in cell layout. This shows TCFF has no disadvantage in P&R process.

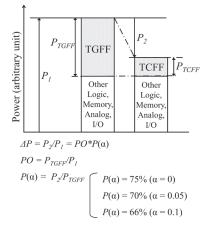


Fig. 25. Power reduction estimation in a chip.

From these results, it is shown that the TCFF can easily replace TGFF while keeping timing performance and almost the same area size. As regards total chip-level power reduction rate, it strongly depends on the application. In general, the power-reduction ef- fect by introducing TCFF is estimated by the following formula (see Fig. 25):

$$\Delta P = PO = RP = P[H]$$

where ΔP is chip power reduction ratio PO is FF occupation ratio, RP is replacement rate, and P is power reduction ratio of FF with data activity (i). In the experimental chip layout, FF occupation ratio in random logic is 44%, RP is 98%, and P (ii 10%) is 66%. Therefore, assuming the ratio of random logic power to the whole chip is 60%, 17% chip power reduction ratio (ΔP) is expected.

VII.COUNTERMEASURE TO VARIOUS SPEED SYSTEMS

In Section VI, we investigated the effect when applying to a250 MHz system design in 40 nm CMOS technology.



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In this section, we show how effectively TCFF is applied to various systems especially to a higher speed case in terms of power and performance. Fig. 26 shows the result about replacement rate of TGFF to TCFF in various clock frequencies. The same front-end cell libraries and netlists as Section VI are used, and only clock cycle condition is set up from 200 MHz to 333 MHz

TABLE IV:PERFORMANCE OF TGFF,TCFF AND RESIZED TCFF.

	CP-Q delay	setup	hold	power (α=10%)
TGFF	183	38	-15	1.00
TCFF	176	105	-69	0.34
TCFF resized	167	83	-57	0.47

Unit of performance : ps

as a parameter. In the condition from 200 MHz to 300 MHz, more than 98% of TGFF are replaced to TCFF. However, in case of 333 MHz condition, replacement rate goes down to 88%, probably because of setup timing issue. Finally, at 360 MHz the timing constraint is not satisfied even if TGFFs are fully used. In order to use TCFF around the critical condition, adjustment of transistor size is considered.

In TCFF, since data-input or data-output operation is controlled by three clock-related tran- sistors, by changing the size of those transistors, performance can be changed. Changing only three transistors in 21 transistors of a TCFF circuit does not affect cell area much. Table IV shows performance of TGFF, TCFF, and the resized TCFF.

In the resized TCFF, only the three clock-related transistors are doubled in size. Fig. 27 shows the normalized power dissipation for TCFF and the resized TCFF compared to TGFF. Compared to the original TCFF, delay and setup time is improved by 5% and 21%, respectively, in the resized TCFF. Power dissipation increases 39%, but is still 53% lower than TGFF.

Fig. 28 shows the result of replacement in 333 MHz clock frequency including the resized TCFF in addition to TGFF and the original TCFF. Total replacement rate is as much as 95%, and 88% is replaced by the original TCFF and 7% is replaced by the resized TCFF. In summary, including a variety of clock-related transistor sizes, TCFF can be applied to various speed systems, and it can reduce whole chip power more effectively.

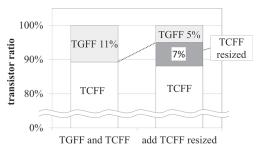


Fig. 26. Frequency dependence of replacement from TGFF to TCFF and the resized TCFF.

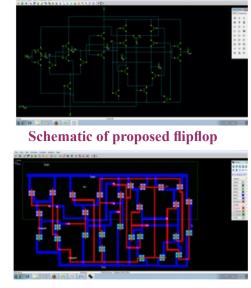
VIII. CONCLUSION:

An extremely low-power FF, TCFF, is proposed with topo- logical compression design methodology. TCFF has the lowest power dissipation in almost all range of the data activity compared with other low-power FFs. The power dissipation of TCFF is 75% lower than that of TGFF at 0% data activity without area overhead. The topology of TCFF is easily ex- pandable to various kinds of FFs without performance penalty. Applying to a 250 MHz experimental chip design with 40 nmCMOS technology, 98% of conventional FFs are replaced by TCFFs. In a whole chip, 17% power reduction is estimated with little overhead of area and timing performance.

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Results



Layout of proposed flipflop

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